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# Dual high-speed switching diode Rev. 5 — 6 March 2012

Product data sheet

## **Product profile**

#### 1.1 General description

Dual high-speed switching diode, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features and benefits

- High switching speed:  $t_{rr} \le 4$  ns
- Repetitive peak reverse voltage:  $V_{RRM} \leq 85 \ V$
- Reverse voltage: V<sub>R</sub> ≤ 80 V
- AEC-Q101 qualified

- Low capacitance: C<sub>d</sub> ≤ 1.5 pF
- Repetitive peak forward current:  $I_{FRM} \le 500 \text{ mA}$
- Very small SMD plastic package

#### 1.3 Applications

- High-speed switching
- General-purpose switching

#### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol          | Parameter             | Conditions             | Min          | Тур | Max | Unit |
|-----------------|-----------------------|------------------------|--------------|-----|-----|------|
| Per diode       |                       |                        |              |     |     |      |
| I <sub>F</sub>  | forward current       |                        | <u>[1]</u>   |     |     |      |
|                 |                       |                        | [2] _        | -   | 250 | mA   |
|                 |                       |                        | [3] _        | -   | 160 | mA   |
| $I_R$           | reverse current       | $V_{R} = 80 \text{ V}$ | -            | -   | 0.5 | μΑ   |
| $V_R$           | reverse voltage       |                        | -            | -   | 80  | V    |
| t <sub>rr</sub> | reverse recovery time |                        | <u>[4]</u> _ | -   | 4   | ns   |

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

- [2] Single diode loaded.
- [3] Double diode loaded.
- [4] When switched from  $I_F = 10$  mA to  $I_R = 10$  mA;  $R_L = 100$   $\Omega$ ; measured at  $I_R = 1$  mA.



#### **Dual high-speed switching diode**

## 2. Pinning information

Table 2. Pinning

| Table 2. | Filling         |                    |                  |
|----------|-----------------|--------------------|------------------|
| Pin      | Description     | Simplified outline | Graphic symbol   |
| 1        | anode (diode 1) |                    |                  |
| 2        | anode (diode 2) | 3                  | 3                |
| 3        | common cathode  | 1 2                | 1 2<br>006aab034 |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |  |         |
|-------------|---------|--|---------|
|             | Name    | Description                              | Version |
| 1PS301      | SC-70   | plastic surface-mounted package; 3 leads | SOT323  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| 1PS301      | B*3                         |

<sup>[1] \* =</sup> placeholder for manufacturing site code

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                       | Conditions                                      | Min        | Max | Unit |
|------------------|---------------------------------|---|------------|-----|------|
| Per diode        |                                 |   |            |     |      |
| $V_{RRM}$        | repetitive peak reverse voltage |   | -          | 85  | V    |
| $V_R$            | reverse voltage                 |   | -          | 80  | V    |
| I <sub>F</sub>   | forward current                 |   | <u>[1]</u> |     |      |
|                  |                                 |   | [2] -      | 250 | mA   |
|                  |                                 |   | [3] _      | 160 | mA   |
| I <sub>FRM</sub> | repetitive peak forward current | $t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$ | -          | 500 | mA   |
| I <sub>FSM</sub> | non-repetitive peak forward     | square wave                                     | <u>[4]</u> |     |      |
|                  | current                         | t <sub>p</sub> = 1 μs                           | -          | 4   | А    |
|                  |                                 | t <sub>p</sub> = 1 s                            | -          | 0.5 | А    |

1PS30

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#### **Dual high-speed switching diode**

 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions                  | Min          | Max  | Unit |
|------------------|-------------------------|-----------------------------|--------------|------|------|
| Per device       |                         |                             |              |      |      |
| P <sub>tot</sub> | total power dissipation | $T_{amb} \le 25  ^{\circ}C$ | <u>[1]</u> _ | 300  | mW   |
| Tj               | junction temperature    |                             | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature     |                             | -55          | +150 | °C   |
| T <sub>stg</sub> | storage temperature     |                             | -65          | +150 | °C   |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

#### 6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol                | Parameter  | Conditions  | Min          | Тур | Max | Unit |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Per device            |  |             |              |     |     |      |
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient      | in free air | <u>[1]</u> _ | -   | 415 | K/W  |
| R <sub>th(j-sp)</sub> | thermal resistance from junction to solder point |             | -            | -   | 200 | K/W  |

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

#### 7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

| Symbol                         | Parameter                | Conditions                                       | Min          | Тур | Max  | Unit |
|--------------------------------|--------------------------|--|--------------|-----|------|------|
| Per diode                      | 9                        |  |              |     |      |      |
| $V_{F}$                        | forward voltage          | I <sub>F</sub> = 1 mA                            | -            | 610 | -    | mV   |
|                                |                          | I <sub>F</sub> = 10 mA                           | -            | 740 | -    | mV   |
|                                |                          | I <sub>F</sub> = 50 mA                           | -            | -   | 1.0  | V    |
|                                |                          | I <sub>F</sub> = 100 mA                          | -            | -   | 1.2  | V    |
| I <sub>R</sub> reverse current | V <sub>R</sub> = 25 V    | -  | -            | 30  | nA   |      |
|                                |                          | V <sub>R</sub> = 80 V                            | -            | -   | 0.5  | μΑ   |
|                                |                          | V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C   | -            | -   | 30   | μΑ   |
|                                |                          | $V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$ | -            | -   | 100  | μΑ   |
| $C_d$                          | diode capacitance        | $f = 1 MHz; V_R = 0 V$                           | -            | -   | 1.5  | pF   |
| t <sub>rr</sub>                | reverse recovery time    |  | <u>[1]</u> _ | -   | 4    | ns   |
| $V_{FR}$                       | forward recovery voltage |  | [2] _        | -   | 1.75 | V    |
| $V_{FR}$                       | forward recovery voltage |  | [2] -        | -   | 1.75 | V    |

<sup>[1]</sup> When switched from  $I_F$  = 10 mA to  $I_R$  = 10 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 1 mA.

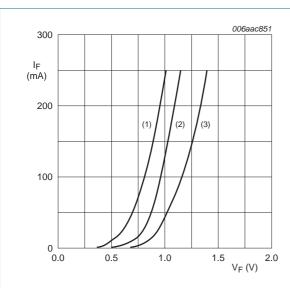
<sup>[2]</sup> Single diode loaded.

<sup>[3]</sup> Double diode loaded.

<sup>[4]</sup>  $T_j = 25$  °C before surge.

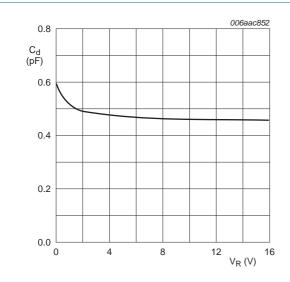
<sup>[2]</sup> When switched from  $I_F = 10$  mA;  $t_r = 20$  ns.

#### **Dual high-speed switching diode**



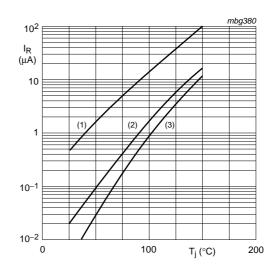
- (1)  $T_i = 150 \,^{\circ}\text{C}$ ; typical values
- (2)  $T_i = 25 \,^{\circ}C$ ; typical values
- (3)  $T_i = 25 \, ^{\circ}C$ ; maximum values

Fig 1. Forward current as a function of forward voltage



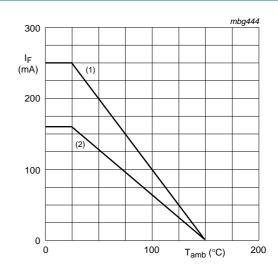
 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1)  $V_R = 80 \text{ V}$ ; maximum values
- (2) V<sub>R</sub> = 80 V; typical values
- (3)  $V_R = 25 V$ ; typical values

Fig 2. Reverse current as a function of junction temperature



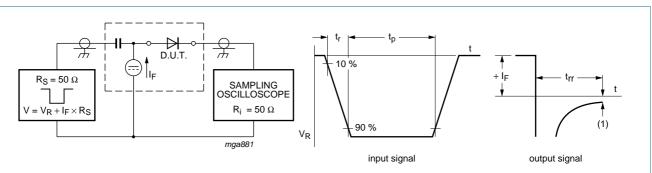
FR4 PCB, standard footprint

- (1) single diode loaded
- (2) double diode loaded

Fig 4. Forward current as a function of ambient temperature; derating curves

#### **Dual high-speed switching diode**

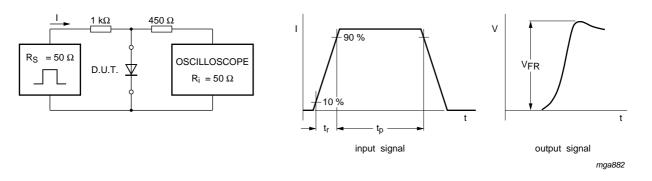
#### 8. Test information



(1)  $I_R = 1 \text{ mA}$ 

Input signal: reverse pulse rise time  $t_r$  = 0.6 ns; reverse voltage pulse duration  $t_p$  = 100 ns; duty cycle  $\delta$  = 0.05 Oscilloscope: rise time  $t_r$  = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time  $t_r$  = 20 ns; forward current pulse duration  $t_p \ge 100$  ns; duty cycle  $\delta \le 0.005$ 

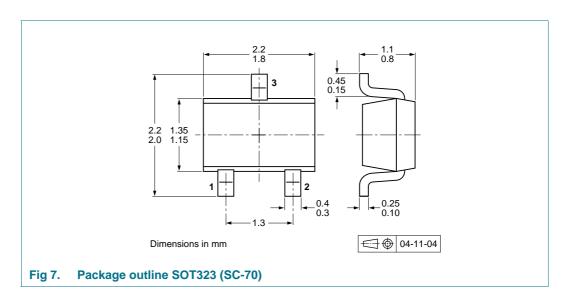
Fig 6. Forward recovery voltage test circuit and waveforms

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### **Dual high-speed switching diode**

## 9. Package outline



## 10. Packing information

Table 8. Packing methods

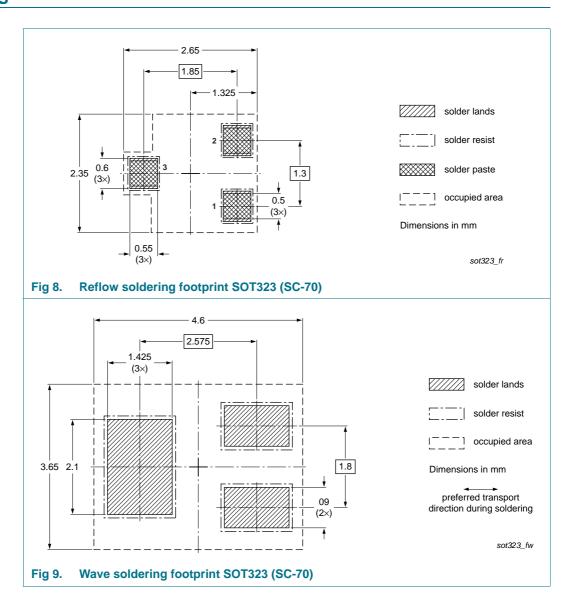
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                    | Packing q | uantity |
|-------------|---------|--------------------------------|-----------|---------|
|             |         |                                | 3000      | 10000   |
| 1PS301      | SOT323  | 4 mm pitch, 8 mm tape and reel | -115      | -135    |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

#### **Dual high-speed switching diode**

## 11. Soldering



## Dual high-speed switching diode

## 12. Revision history

Table 9. Revision history

|                | •                                       |   |                       |                       |  |  |
|----------------|---|---|-----------------------|-----------------------|--|--|
| Document ID    | Release date                            | Data sheet status                                     | Change notice         | Supersedes            |  |  |
| 1PS301 v.5     | 20120306                                | Product data sheet                                    | -                     | 1PS301 v.4            |  |  |
| Modifications: |   | of this document has been r<br>of NXP Semiconductors. | edesigned to comply v | with the new identity |  |  |
|                | <ul> <li>Legal texts</li> </ul>         | have been adapted to the n                            | ew company name wh    | ere appropriate.      |  |  |
|                | <ul><li>Section 1.1</li></ul>           | "General description": amer                           | nded                  |                       |  |  |
|                | • Table 1 "Qu                           | Table 1 "Quick reference data": added                 |                       |                       |  |  |
|                | Section 4 "Marking": updated            |   |                       |                       |  |  |
|                | Section 8 "Test information": added     |   |                       |                       |  |  |
|                | • Figure 7: su                          | perseded by minimized pac                             | kage outline drawing  |                       |  |  |
|                | Section 10 "Packing information": added |   |                       |                       |  |  |
|                | Section 11 "Soldering": added           |   |                       |                       |  |  |
|                | <ul> <li>Section 13 '</li> </ul>        | <u>'Legal information"</u> : updated                  |                       |                       |  |  |
| 1PS301 v.4     | 19990506                                | Product data sheet                                    | -                     | 1PS301 v.3            |  |  |
| 1PS301 v.3     | 19961004                                | Product specification                                 | -                     | 1PS301 v.2            |  |  |
| 1PS301 v.2     | 19960903                                | Product specification                                 | -                     | 1PS301 v.1            |  |  |
| 1PS301 v.1     | 19960403                                | Product specification                                 | -                     | -                     |  |  |
|                |   |   |                       |                       |  |  |

#### **Dual high-speed switching diode**

### 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
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#### **Dual high-speed switching diode**

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